

## INCHANGE SEMICONDUCTOR

## isc N-Channel MOSFET Transistor

# **FKP253**

### • FEATURES

- With TO-220F packaging
- High speed switching
- · Low gate input resistance
- Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

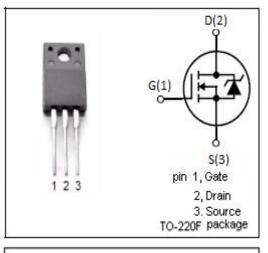
- Power supply
- Switching applications

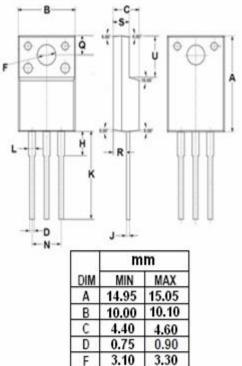
• ABSOL				
SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	250	V	
V <sub>GSS</sub>	Gate-Source Voltage	±30	∧v	
ID	Drain Current-Continuous	20	A	
I <sub>DM</sub>	Drain Current-Single Pulsed	80	А	
PD	Total Dissipation	40	W	
Tj	Operating Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	°C	

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ		
Rth(ch-c)	Channel-to-case thermal resistance	3.13	°C <b>/W</b>	
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W	

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Н

J

K

L

Ν

Q

R

SU

3.70

0.50

13.4

1.10

5.00

2.70

2.20

2.65

6.40

3.90

0.70

13.6

1.30

5.20

2.90

2.40

2.90

6.60

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### ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.1mA	250			v
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =1.0mA	3.0		4.5	v
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =10A		86	95	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±30V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 250V; V <sub>GS</sub> = 0V;			100	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =20A, V <sub>GS</sub> = 0 V			1.5	V

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